



APT40M75JN Information

Heisener.com

Part Number APT40M75JN

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 400V 56A ISOTOP

SOT-227-4, miniBLOC **Package**

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com For Reference Only

E-mail: salesdept@heisener.com



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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









APT40M75JN Specifications

Manufacturer Part NumberAPT40M75JNManufacturerMicrosemi CorporationCategoryDiscrete Semiconductor ProductsTransistors - FETs, MOSFETs - SinglePackageSOT-227-4, miniBLOCSeriesPOWER MOS IV?FET TypeN-ChannelTechnologyMOSFET (Metal Oxide)Drain to Source Voltage (Vdss)400VCurrent - Continuous Drain (Id) @ 25°C56A (Tc)Drive Voltage (Max Rds On, Min Rds On)10V	
Category Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single SOT-227-4, miniBLOC Series POWER MOS IV? FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) Current - Continuous Drain (Id) @ 25°C Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single SOT-227-4, miniBLOC POWER MOS IV? N-Channel MOSFET (Metal Oxide) 56A (Tc)	
Transistors - FETs, MOSFETs - Single Package SOT-227-4, miniBLOC Series POWER MOS IV? FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 400V Current - Continuous Drain (Id) @ 25°C 56A (Tc)	
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Series POWER MOS IV? FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 400V Current - Continuous Drain (Id) @ 25°C 56A (Tc)	
FET Type N-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) 400V Current - Continuous Drain (Id) @ 25°C 56A (Tc)	
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Drain to Source Voltage (Vdss) Current - Continuous Drain (Id) @ 25°C 56A (Tc)	
Current - Continuous Drain (Id) @ 25°C 56A (Tc)	
Drive Voltage (Max Rds On Min Rds On)	
Dive votage (Man Rus On, Min Rus On)	
Vgs(th) (Max) @ Id 4V @ 2.5mA	
Gate Charge (Qg) (Max) @ Vgs 370nC @ 10V	
Input Capacitance (Ciss) (Max) @ Vds 6800pF @ 25V	
Vgs (Max) ±30V	
FET Feature -	
Power Dissipation (Max) 520W (Tc)	
Rds On (Max) @ Id, Vgs 75 mOhm @ 28A, 10V	
Operating Temperature $-55^{\circ}\text{C} \sim 150^{\circ}\text{C} \text{ (TJ)}$	
Mounting Type Chassis Mount	
Supplier Device Package ISOTOP?	
Package / Case SOT-227-4, miniBLOC	

APT40M75JN Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

APT40M75JN Payment Methods



















APT40M75JN Shipping Methods













If you have any question about APT40M75JN, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com